

NCE85H35TC

NCE N-Channel Enhancement Mode Power MOSFET

Description

The NCE85H35TC uses advanced trench technology and design to provide excellent $R_{\text{DS(ON)}}$ with low gate charge. It can be used in automotive applications and a wide variety of other applications.

General Features

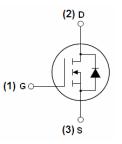
- V_{DSS} =85V,I_D =350A
 - $R_{DS(ON)} < 2.4 \text{m}\Omega @ V_{GS} = 10V \text{ (Typ: } 1.8 \text{ m}\Omega)$
- Good stability and uniformity with high E_{AS}
- Special process technology for high ESD capability
- High density cell design for ultra low Rdson
- Fully characterized avalanche voltage and current
- Excellent package for good heat dissipation

Application

- Automotive applications
- Hard switched and high frequency circuits
- Uninterruptible power supply

100% UIS TESTED!

100% ΔVds TESTED!



Schematic diagram



Marking and pin assignment



TO-247 top view

Package Marking and Ordering Information

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
NCE85H35TC	NCE85H35TC	TO-247	-	-	-

Absolute Maximum Ratings (T_C=25 ℃unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	VDSS	85	V
Gate-Source Voltage	V _{GS}	±20	V
Drain Current-Continuous	I _D	350	А
Drain Current-Continuous(T _C =100 °C)	I _D (100℃)	247	Α
Pulsed Drain Current	I _{DM}	1280	Α
Maximum Power Dissipation	P _D	460	W
Derating factor		3.07	W/°C
Single pulse avalanche energy (Note 3)	E _{AS}	3500	mJ
Operating Junction and Storage Temperature Range	T_{J} , T_{STG}	-55 To 175	$^{\circ}$ C



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Thermal Characteristic

Thermal Resistance, Junction-to-Case (Note 1)	$R_{ heta JC}$	0.33	°C/W	
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Electrical Characteristics (T_C=25 °C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics	·					
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V I _D =250μA	85	90	-	V
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =85V,V _{GS} =0V	-	-	1	μA
Gate-Body Leakage Current	I _{GSS}	V _{GS} =±20V,V _{DS} =0V	-	-	±200	nA
On Characteristics	·					
Gate Threshold Voltage	V _{GS(th)}	V_{DS} = V_{GS} , I_D =250 μ A	2.5	3.6	4.5	V
Drain-Source On-State Resistance	R _{DS(ON)}	V _{GS} =10V, I _D =40A	-	1.8	2.4	mΩ
Forward Transconductance	g FS	V _{DS} =10V,I _D =20A	45	-	-	S
Dynamic Characteristics			•			•
Input Capacitance	C _{lss}	\/ -25\/\/ -0\/	-	16000	-	PF
Output Capacitance	Coss	V_{DS} =25V, V_{GS} =0V, F=1.0MHz	-	1352	-	PF
Reverse Transfer Capacitance	C _{rss}	F=1.UIVIH2	-	1061	-	PF
Switching Characteristics	·					
Turn-on Delay Time	t _{d(on)})/ 00\/ L 40A	-	43	-	nS
Turn-on Rise Time	t _r	V_{DD} =38V, I_{D} =40A V_{GS} =10V, R_{GEN} =1.2 Ω	-	220	-	nS
Turn-Off Delay Time	t _{d(off)}	(Note2)	-	170	-	nS
Turn-Off Fall Time	t _f		-	260	-	nS
Total Gate Charge	Qg	\/ -20\/ I -20A	-	469	-	nC
Gate-Source Charge	Q _{gs}	V_{DS} =30V, I_{D} =30A, V_{GS} =10V ^(Note2)	-	99	-	nC
Gate-Drain Charge	Q _{gd}	VGS-10V	-	148	-	nC
Drain-Source Diode Characteristics			•			
Diode Forward Voltage	V _{SD}	V _{GS} =0V,I _S =40A	-	-	1.2	V
Reverse Recovery Time	t _{rr}	TJ = 25°C, IF = 40A	-	87.9	-	nS
Reverse Recovery Charge	Qrr	$di/dt = 100A/\mu s^{(Note2)}$	-	129	-	nC
Forward Turn-On Time	t _{on}	Intrinsic turn-on time is negligible (turn-on is dominated by LS+LD)				

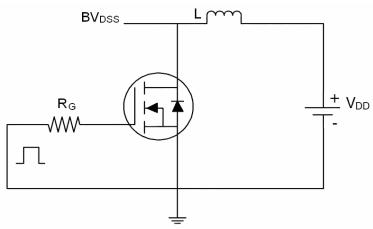
Notes:

- 1. Surface Mounted on FR4 Board, t ≤ 10 sec.
- 2. Pulse Test: Pulse Width \leq 400 μ s, Duty Cycle \leq 2%.
- 3. EAS condition: Tj=25 $^{\circ}\text{C}$,VDD=42.5V,VG=10V,L=1mH,Rg=25 Ω
- 4. Isd \leqslant 125A, di/dt \leqslant 260A/ μ s, Vdd \leqslant V(BR)dss, TJ \leqslant 175°C

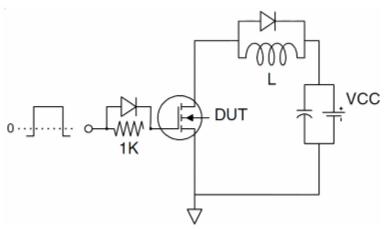
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Test Circuit

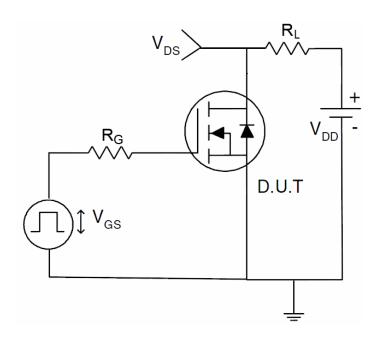
1) E_{AS} test circuit



2) Gate charge test circuit



3) Switch time test circuit





Typical Electrical and Thermal Characteristics

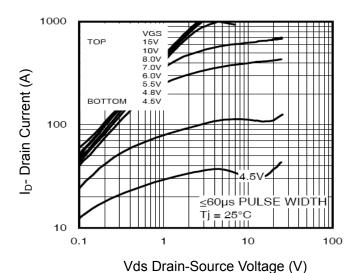
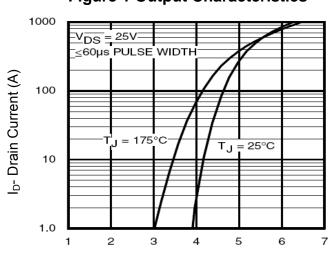


Figure 1 Output Characteristics



Vgs Gate-Source Voltage (V)

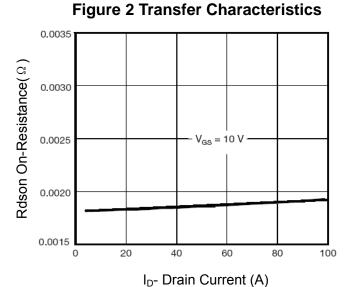
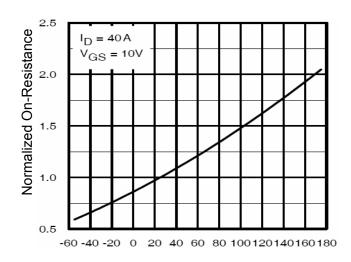


Figure 3 Rdson- Drain Current



T_J-Junction Temperature(°ℂ)

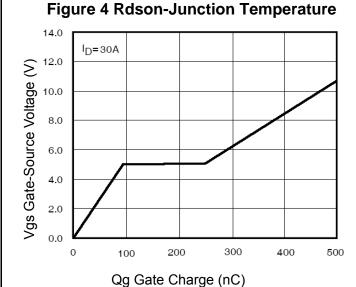


Figure 5 Gate Charge

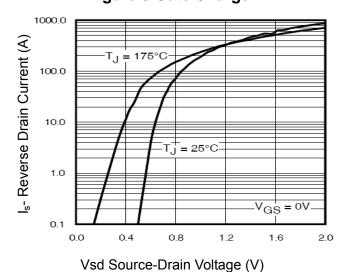


Figure 6 Source- Drain Diode Forward



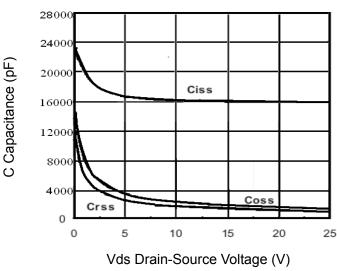


Figure 7 Capacitance vs Vds

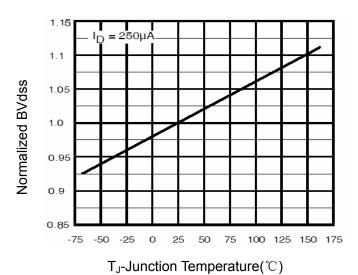


Figure 9 BV_{DSS} vs Junction Temperature

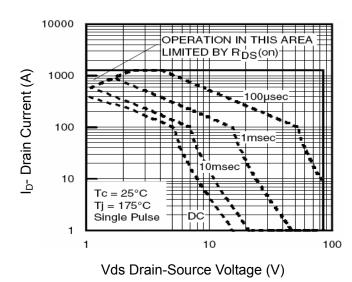


Figure 8 Safe Operation Area

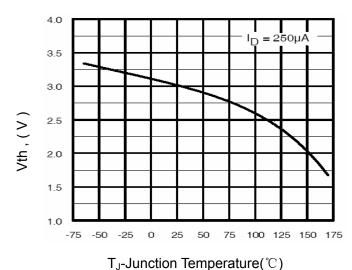
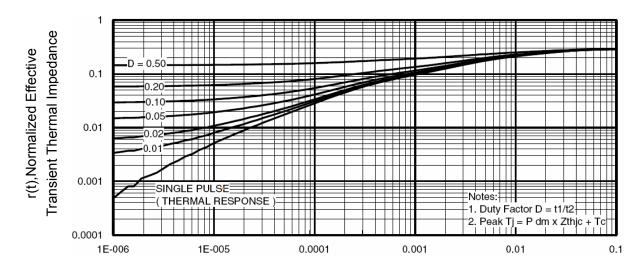


Figure 10 V_{GS(th)} vs Junction Temperature

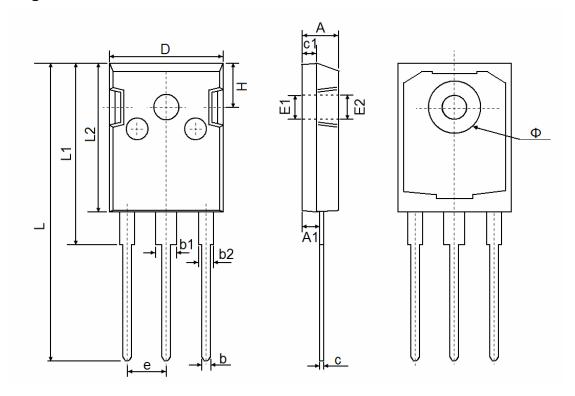


Square Wave Pluse Duration(sec)

Figure 11 Normalized Maximum Transient Thermal Impedance



TO-247 Package Information



Symbol	Dimensions	In Millimeters	Dimensions In Inches		
Symbol	Min.	Max.	Min.	Max.	
А	4.850	5.150	0.191	0.200	
A1	2.200	2.600	0.087	0.102	
b	1.000	1.400	0.039	0.055	
b1	2.800	3.200	0.110	0.126	
b2	1.800	2.200	0.071	0.087	
С	0.500	0.700	0.020	0.028	
c1	1.900	2.100	0.075	0.083	
D	15.450	15.750	0.608	0.620	
E1	3.500) REF	0.138 REF		
E2	3.600 REF		0.142	REF	
L	40.900	41.300	1.610	1.626	
L1	24.800	25.100	0.976	0.988	
L2	20.300	20.600	0.799	0.811	
Ф	7.100	7.300	0.280	0.287	
е	5.450) TYP	0.215 TYP		
Н	5.980) REF	0.235 REF		

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